



BUK9215-55A

N-channel TrenchMOS logic level FET

7 April 2014

Product data sheet

1. General description

Logic level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product has been designed and qualified to the appropriate AEC standard for use in automotive critical applications.

2. Features and benefits

- AEC Q101 compliant
- Low conduction losses due to low on-state resistance
- Suitable for logic level gate drive sources
- Suitable for thermally demanding environments due to 175 °C rating

3. Applications

- 12 V and 24 V loads
- Automotive and general purpose power switching
- Motors, lamps and solenoids

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25^\circ\text{C}$; $T_j \leq 175^\circ\text{C}$		-	-	55	V
I_D	drain current	$V_{GS} = 5\text{ V}$; $T_{mb} = 25^\circ\text{C}$; Fig. 2 ; Fig. 3	[1]	-	-	62	A
P_{tot}	total power dissipation	$T_{mb} = 25^\circ\text{C}$; Fig. 1		-	-	115	W
Static characteristics							
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10\text{ V}$; $I_D = 25\text{ A}$; $T_j = 25^\circ\text{C}$		-	11	13.6	$\text{m}\Omega$
		$V_{GS} = 4.5\text{ V}$; $I_D = 25\text{ A}$; $T_j = 25^\circ\text{C}$		-	-	16.6	$\text{m}\Omega$
		$V_{GS} = 5\text{ V}$; $I_D = 25\text{ A}$; $T_j = 25^\circ\text{C}$; Fig. 11 ; Fig. 12		-	13	15	$\text{m}\Omega$
Dynamic characteristics							
Q_{GD}	gate-drain charge	$V_{GS} = 5\text{ V}$; $I_D = 25\text{ A}$; $V_{DS} = 44\text{ V}$; $T_j = 25^\circ\text{C}$; Fig. 9		-	20	-	nC

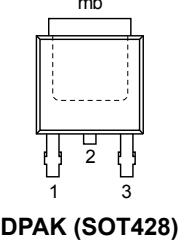
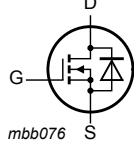
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Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Avalanche ruggedness							
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 62 \text{ A}$; $V_{sup} \leq 55 \text{ V}$; $R_{GS} = 50 \Omega$; $V_{GS} = 5 \text{ V}$; $T_{j(init)} = 25 \text{ }^\circ\text{C}$; unclamped		-	-	211	mJ

[1] Current is limited by power dissipation chip rating.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	drain		
3	S	source		
mb	D	mounting base; connected to drain		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BUK9215-55A	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25^\circ\text{C}$; $T_j \leq 175^\circ\text{C}$		-	55	V
V_{DGR}	drain-gate voltage	$R_{GS} = 20\text{ k}\Omega$		-	55	V
V_{GS}	gate-source voltage			-15	15	V
P_{tot}	total power dissipation	$T_{mb} = 25^\circ\text{C}$; Fig. 1		-	115	W
I_D	drain current	$T_{mb} = 25^\circ\text{C}$; $V_{GS} = 5\text{ V}$; Fig. 2 ; Fig. 3	[1]	-	62	A
			[2]	-	55	A
		$T_{mb} = 100^\circ\text{C}$; $V_{GS} = 5\text{ V}$; Fig. 2	[1]	-	44	A
I_{DM}	peak drain current	$T_{mb} = 25^\circ\text{C}$; pulsed; $t_p \leq 10\text{ }\mu\text{s}$; Fig. 3		-	248	A
T_{stg}	storage temperature			-55	175	°C
T_j	junction temperature			-55	175	°C
Source-drain diode						
I_S	source current	$T_{mb} = 25^\circ\text{C}$	[2]	-	55	A
			[1]	-	62	A
I_{SM}	peak source current	pulsed; $t_p \leq 10\text{ }\mu\text{s}$; $T_{mb} = 25^\circ\text{C}$		-	248	A
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 62\text{ A}$; $V_{sup} \leq 55\text{ V}$; $R_{GS} = 50\text{ }\Omega$; $V_{GS} = 5\text{ V}$; $T_{j(init)} = 25^\circ\text{C}$; unclamped		-	211	mJ

[1] Current is limited by power dissipation chip rating.

[2] Continious current is limited by bond wires.

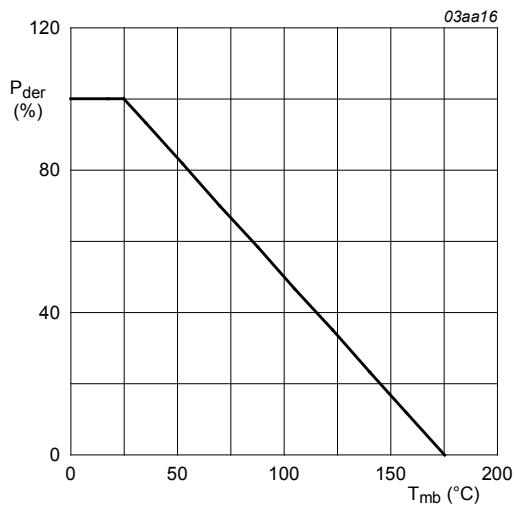


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot}(25^\circ C)} \times 100 \%$$

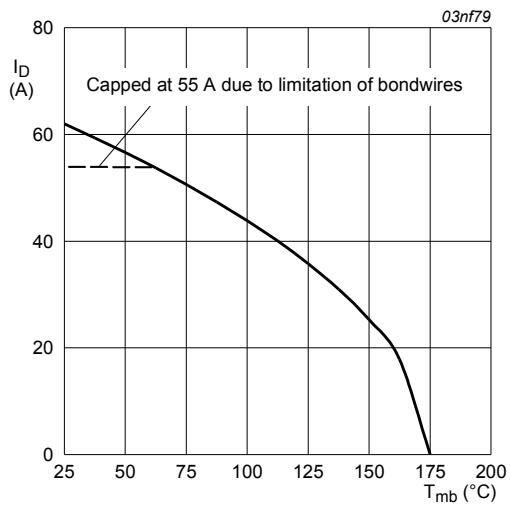


Fig. 2. Continuous drain current as a function of mounting base temperature

$$I_{der} = \frac{I_D}{I_D(25^\circ C)} \times 100 \%$$

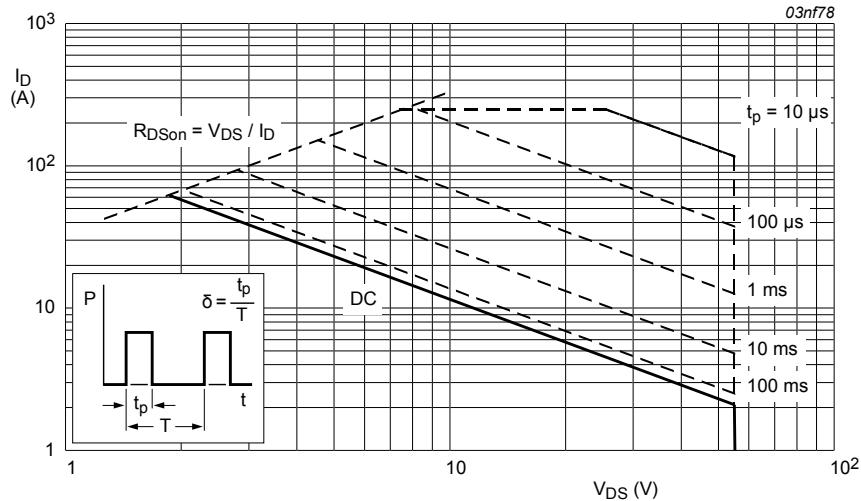


Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{mb} = 25^\circ C$; I_{DM} is single pulse

8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 4		-	-	1.3	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient			-	71.4	-	K/W

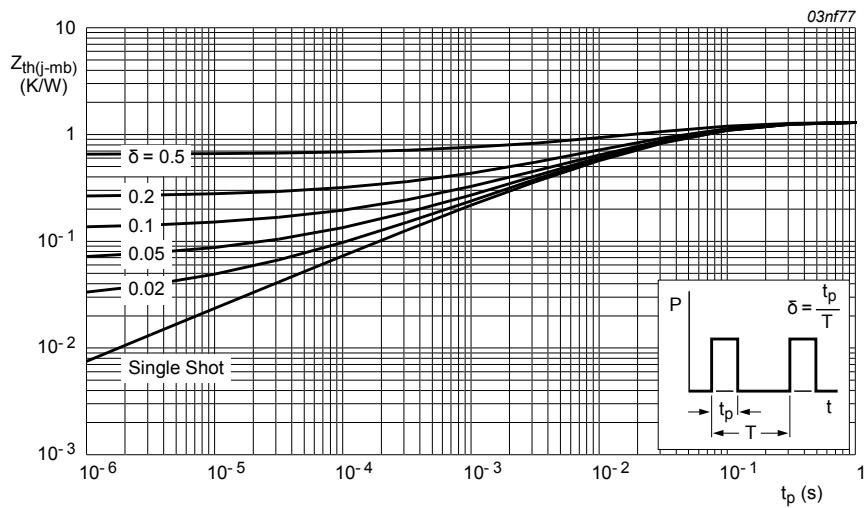


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 0.25 mA; V _{GS} = 0 V; T _j = 25 °C		55	-	-	V
		I _D = 0.25 mA; V _{GS} = 0 V; T _j = -55 °C		50	-	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 1 mA; V _{DS} = V _{GS} ; T _j = -55 °C; Fig. 10		-	-	2.3	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 175 °C; Fig. 10		0.5	-	-	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 25 °C; Fig. 10		1	1.5	2	V
I _{DSS}	drain leakage current	V _{DS} = 55 V; V _{GS} = 0 V; T _j = 25 °C		-	0.05	10	µA
		V _{DS} = 55 V; V _{GS} = 0 V; T _j = 175 °C		-	-	500	µA
I _{GSS}	gate leakage current	V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C		-	2	100	nA
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C		-	2	100	nA
R _{DSON}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C		-	11	13.6	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C		-	-	16.6	mΩ
		V _{GS} = 5 V; I _D = 25 A; T _j = 175 °C; Fig. 11; Fig. 12		-	-	30	mΩ
		V _{GS} = 5 V; I _D = 25 A; T _j = 25 °C; Fig. 11; Fig. 12		-	13	15	mΩ
Dynamic characteristics							
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 44 V; V _{GS} = 5 V; T _j = 25 °C; Fig. 9		-	48	-	nC
Q _{GS}	gate-source charge			-	6	-	nC
Q _{GD}	gate-drain charge			-	20	-	nC
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 25 V; f = 1 MHz; T _j = 25 °C; Fig. 13		-	2190	2916	pF
C _{oss}	output capacitance			-	380	450	pF
C _{rss}	reverse transfer capacitance			-	250	344	pF
t _{d(on)}	turn-on delay time	V _{DS} = 30 V; R _L = 1.2 Ω; V _{GS} = 5 V; R _{G(ext)} = 10 Ω; T _j = 25 °C		-	19	-	ns
t _r	rise time			-	161	-	ns
t _{d(off)}	turn-off delay time			-	138	-	ns
t _f	fall time			-	165	-	ns
L _D	internal drain inductance	measured from drain to centre of die		-	2.5	-	nH

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
L_S	internal source inductance	measured from source lead to source bond pad		-	7.5	-	nH
Source-drain diode							
V_{SD}	source-drain voltage	$I_S = 20 \text{ A}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; Fig. 14		-	0.85	1.2	V
t_{rr}	reverse recovery time	$I_S = 20 \text{ A}$; $dI_S/dt = -100 \text{ A}/\mu\text{s}$		-	51	-	ns
Q_r	recovered charge	$V_{GS} = -10 \text{ V}$; $V_{DS} = 30 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$		-	102	-	nC

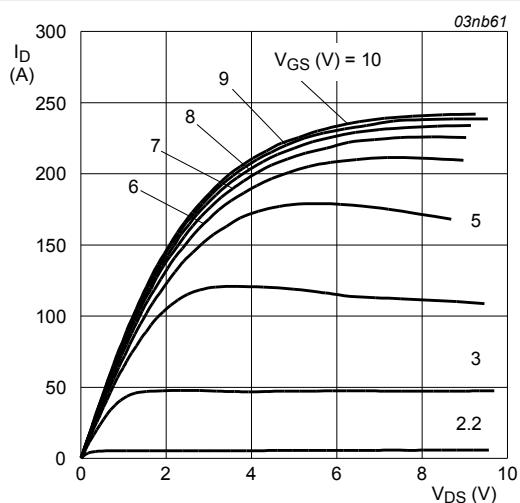


Fig. 5. Output characteristics: drain current as a function of drain-source voltage; typical values

$T_j = 25 \text{ }^\circ\text{C}$

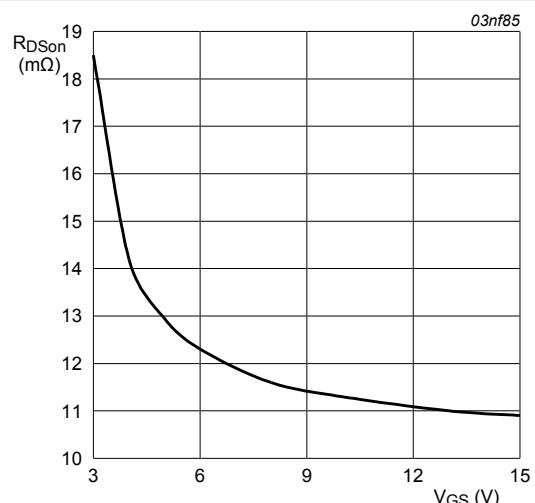


Fig. 6. Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_j = 25 \text{ }^\circ\text{C}; I_D = 25 \text{ A}$

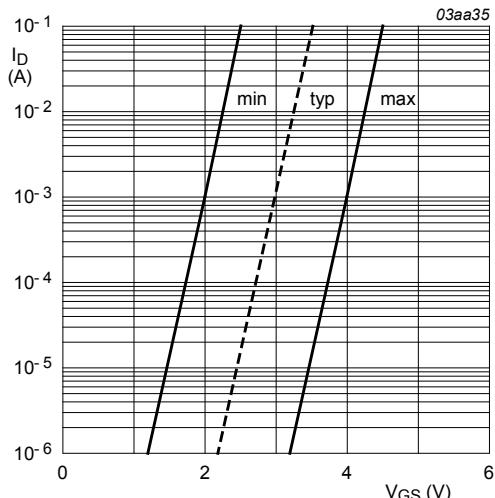


Fig. 7. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25 \text{ }^\circ\text{C}; V_{DS} = 5 \text{ V}$

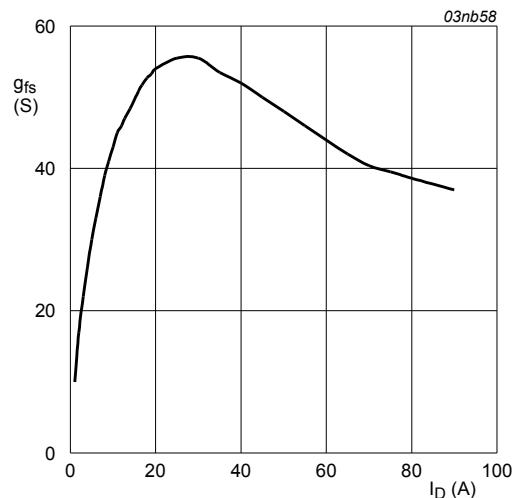


Fig. 8. Forward transconductance as a function of drain current; typical values

$T_j = 25 \text{ }^\circ\text{C}; V_{DS} = 25 \text{ V}$

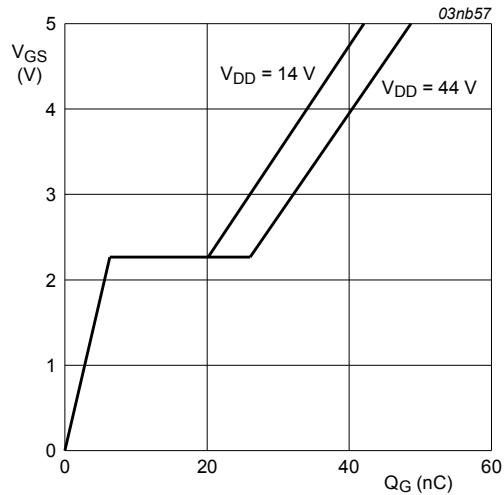


Fig. 9. Gate-source voltage as a function of turn-on gate charge; typical values

$T_j = 25^\circ C; I_D = 25A$

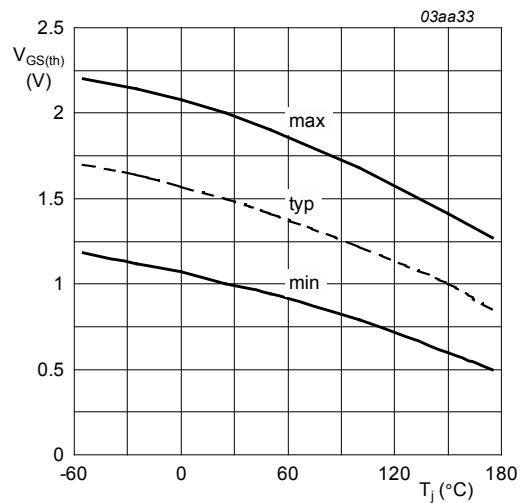


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$I_D = 1mA; V_{DS} = V_{GS}$

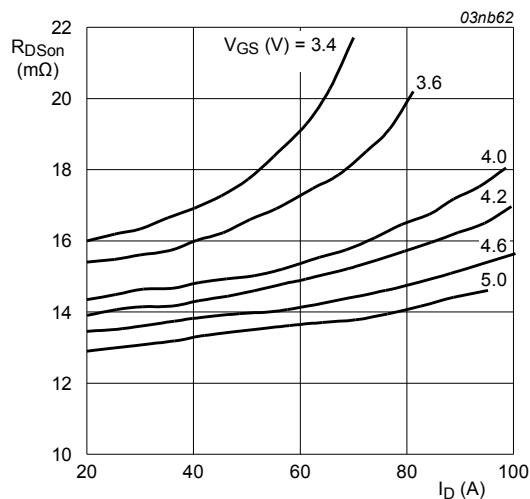


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

$T_j = 25^\circ C$

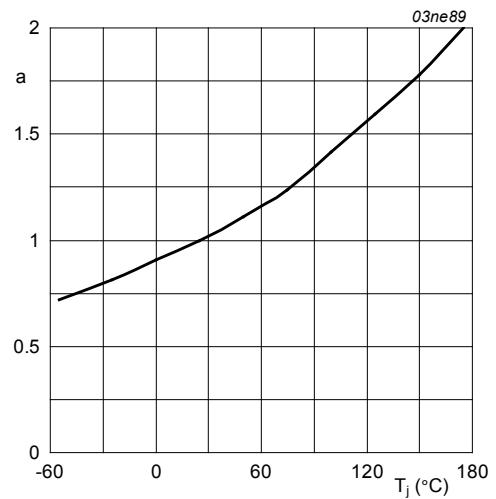


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon}(25^\circ C)}$$

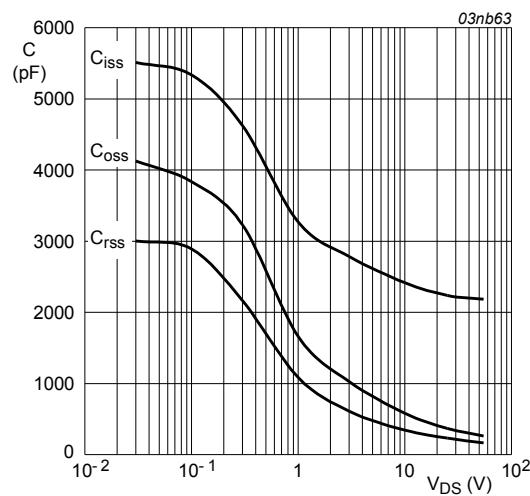


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$V_{GS} = 0V; f = 1MHz$

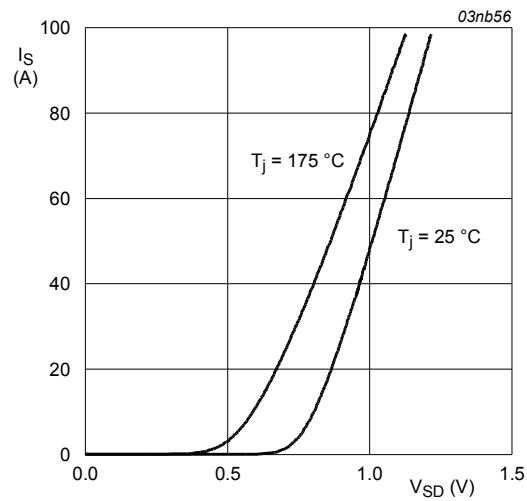


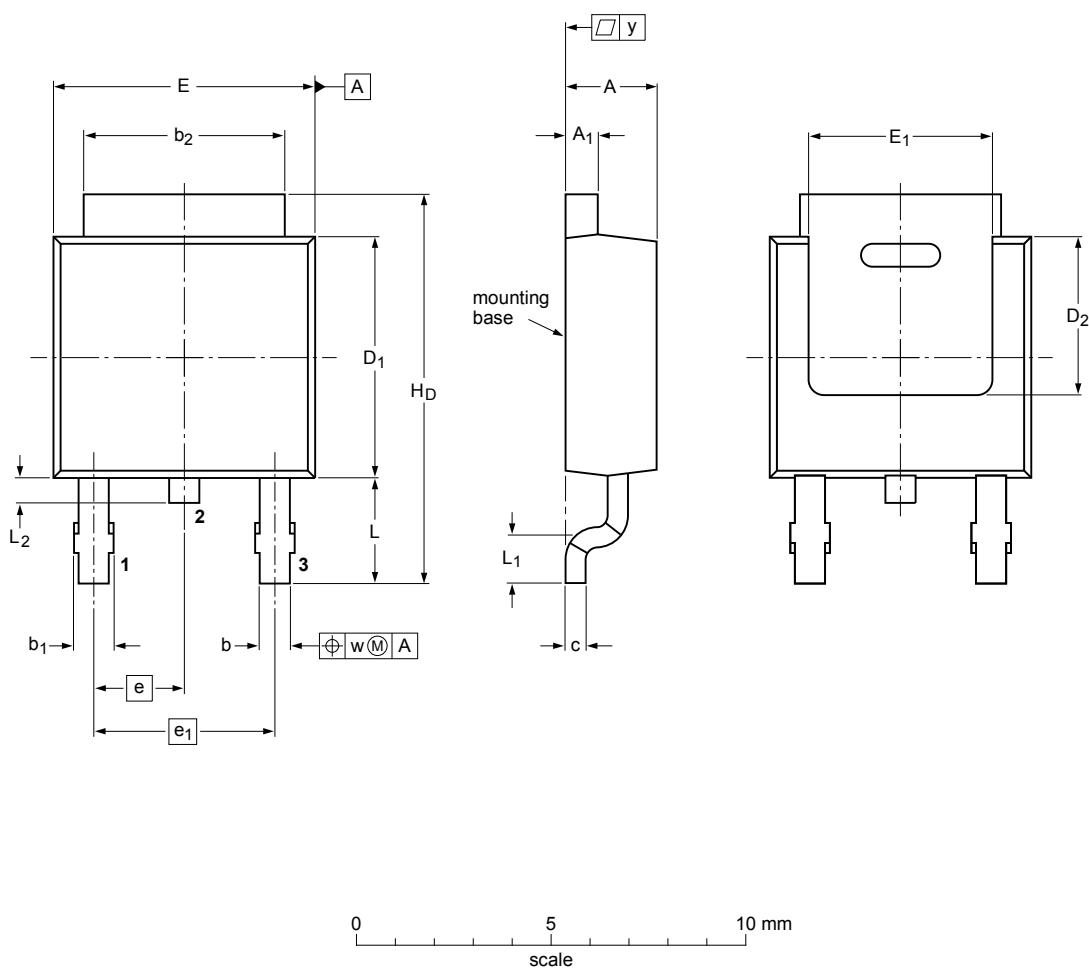
Fig. 14. Reverse diode current; typical value

$V_{GS} = 0V$

10. Package outline

Plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)

SOT428



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁	b	b ₁	b ₂	c	D ₁	D ₂ _{min}	E	E ₁ _{min}	e	e ₁	H _D	L	L ₁ _{min}	L ₂	w	y _{max}
mm	2.38 2.22	0.93 0.46	0.89 0.71	1.1 0.9	5.46 5.00	0.56 0.20	6.22 5.98	4.0 6.47	6.73 4.45	4.45 2.285	2.285 4.57	10.4 9.6	2.95 2.55	0.5 0.5	0.9 0.5	0.2	0.2	0.2

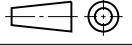
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT428		TO-252	SC-63			-06-02-14 06-03-16

Fig. 15. Package outline DPAK (SOT428)

11. Legal information

11.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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